



SPECIFICATIONS			
<u>DEVICE TYPE NAME</u> SANKEN SILICON SCHOTTKY BARRIER DIODE FMB-24M			
1. Scope The present specifications shall apply to Sanken silicon diode, FMB-24M. 2. General 2.1 Type Silicon Schottky Barrier Diode 2.2 Structure Resin Molded 2.3 Application Pulse Rectification, etc 3. Flammability UL94V-0 (Equivalent) 4. Dimensions, Inner Structure and Marking 4.1 Appearance The body shall be clean and shall not bear any stain, rust or flaw. The color of the case will be black. 4.2 Dimensions Refer to 9.1 4.3 Marking : Refer to 9.2 4.4 Inner Structure : Refer to 9.3			
DATE of PROCESSING		September/28/ 2013	
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		SPECIFICATION NUMBER	1/8
		SSA-03414	

5. Absolute Maximum Ratings

				FMB-24M	
No.	Item	Symbol	Unit	Rating	Conditions
1	Transient Peak Reverse Voltage	V_{RSM}	V	45	
2	Peak Reverse Voltage	V_{RM}	V	40	
3	Average Forward Current	$I_{F(AV)}$	A	6.0	$T_c \leq 123^\circ\text{C}$, Sinewave
4	Peak Surge Forward Current	I_{FSM}	A	60	half sinewave, one shot
5	I^2t Limiting Value	I^2t	A^2s	18	$1\text{msec} \leq t \leq 10\text{msec}$
6	Junction Temperature	T_j	$^\circ\text{C}$	-40~+150	
7	Storage Temperature	T_{stg}	$^\circ\text{C}$	-40~+150	
8	Dielectric Strength		kV	A.C. 1.0	Junction and case(1min.)

6. Electrical Characteristics (Ta=25°C, unless otherwise specified)

No.	Item	Symbol	Unit	Value	Conditions
1	Forward Voltage Drop	V_F	V	0.55 max.	$I_F=3.0\text{A}$
2	Reverse Leakage Current	I_R	mA	3.0 max.	$V_R=V_{RM}$
3	Reverse Leakage Current Under High Temperature	$H \cdot I_{R1}$	mA	30 max.	$V_R=V_{RM}$, $T_j=125^\circ\text{C}$
		$H \cdot I_{R2}$	mA	100 max.	$V_R=V_{RM}$, $T_j=150^\circ\text{C}$
4	Thermal Resistance	$R_{th(j-c)}$	$^\circ\text{C/W}$	4.0 Max.	Between Junction and case

* No.1,2&3 show characteristics per one chip.

7. Reliability Test

7.1 Test Conditions

No.	Item	Rating	Conditions
1	Thermal Fatigue Test	5000 cycles	$\Delta T_j = 100^\circ\text{C}$
2	High Temperature Reverse Bias Test	1000 hours	$T_a = 80^\circ\text{C}$, $V_R = V_{RM}(\text{D.C.})$ With Fin
3	Humidity Reverse Bias Test	500 hours	$T_a = 85^\circ\text{C}$, R.H.=85%, $V_R = V_{RM} \times 0.8(\text{D.C.})$
4	High Temperature Storage Test	1000 hours	$T_a = 150^\circ\text{C}$
5	Moisture Resistance Test	1000 hours	$T_a = 85^\circ\text{C}$, 85%R.H.
6	Thermal Shock Test	100 cycle	Ice-water(5min.) ~ R.T.(30sec.) ~ Boiling-water(5min.)
7	Temperature Cycle Test	100 cycle	$-40^\circ\text{C}(30\text{min.}) \sim +150^\circ\text{C}(30\text{min.})$
8	Pressure Cooker Test	96 hours	$2.03 \times 10^5 \text{Pa}$, 100%R.H., Unsaturated equipment
9	Resistance to Soldering Heat Test	10 sec.	$260 \pm 5^\circ\text{C}$, Dipping up to 1.5mm from case
		3 sec.	$350 \pm 5^\circ\text{C}$, Dipping up to 1.5mm from case
10	Solderability Test	95%	$235 \pm 5^\circ\text{C}$, 5sec., Using rosin flux
11	Lead Bend Test	2 times	Apply EIAJ ED-4701 A-111
12	Lead Pull Test	10 sec.	
13	Lead Twist Test	2 times	
14	Drop Test	10 times	Naturally drop from 1m height on maple plate

7.2 Acceptance Criteria

Base on the fulfillment of electrical characteristics of 6. Lead shall be not cut of No.11, 12 and 13.

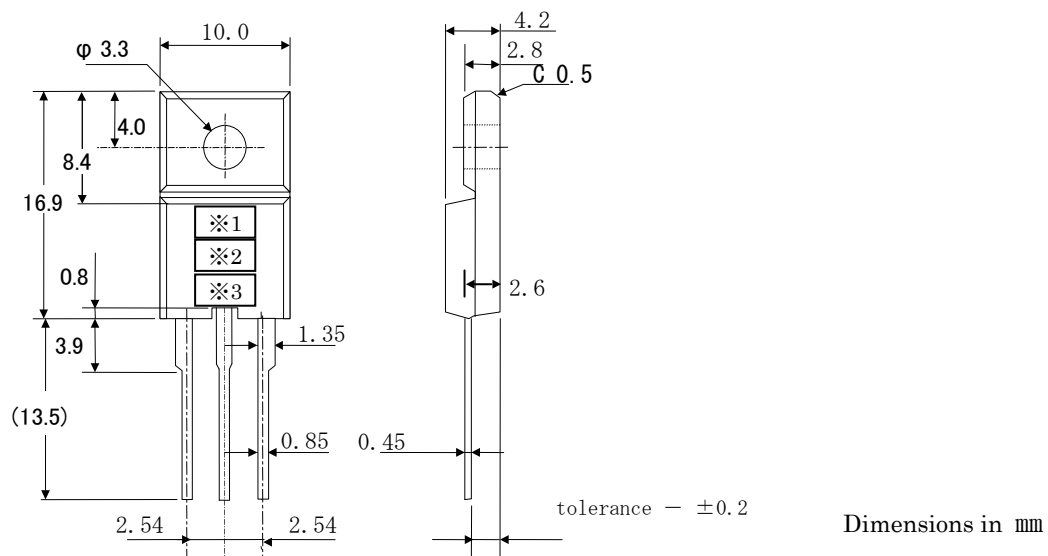
8. Standard Test Condition

Standard test conditions are at $T_a = 25^\circ\text{C}$ and R.H.=60%.

But it is also acceptable to do test under ordinary temperature and ordinary R.H. ($T_a = 5 \sim 35^\circ\text{C}$, R.H.=45~85%)

9. Dimensions, Inner Structure and Marking

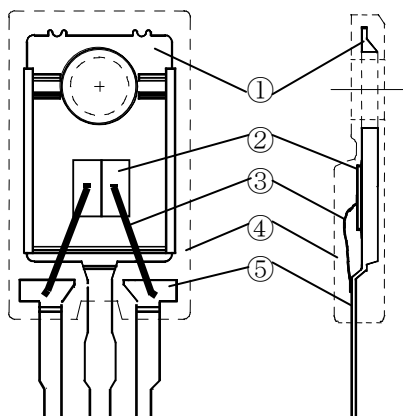
9.1 Dimensions Refer



9.2 Marking

Type Name	Marking		
	* 1 Type Name	* 2 Polarity	* 3 Lot number
FMB-24M	FMB24M		1st letter: Last digit of year 2nd letter: Month From 1 to 9 for Jan. to Sep., O for Oct., N for Nov., D for Dec. 3rd & 4th letter: Day ex. 0125 (Jan.25, 2000)

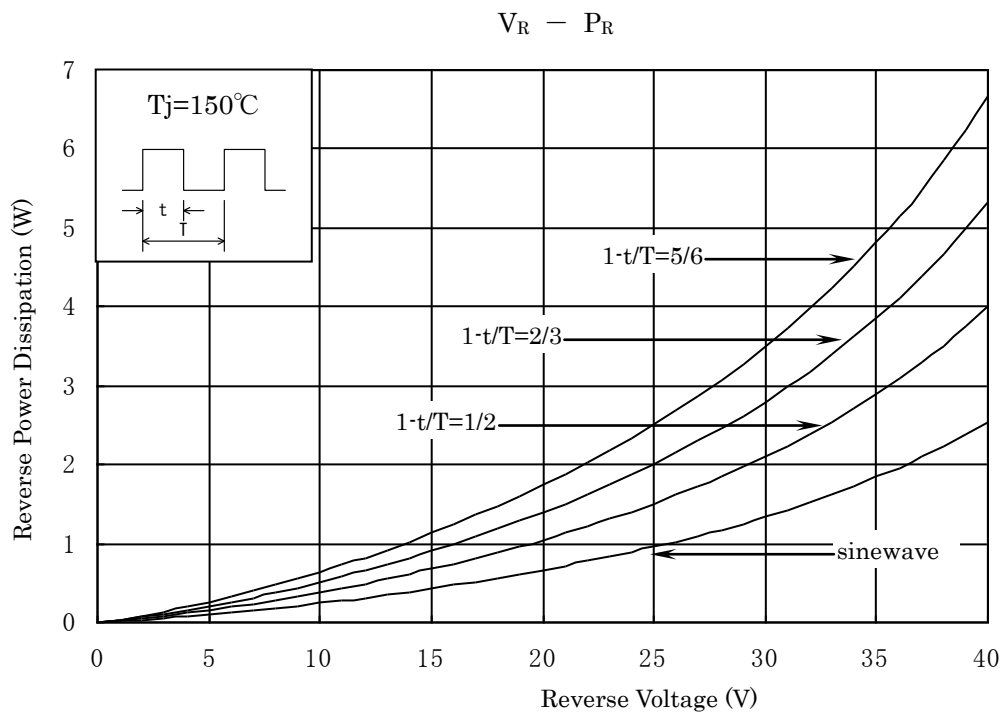
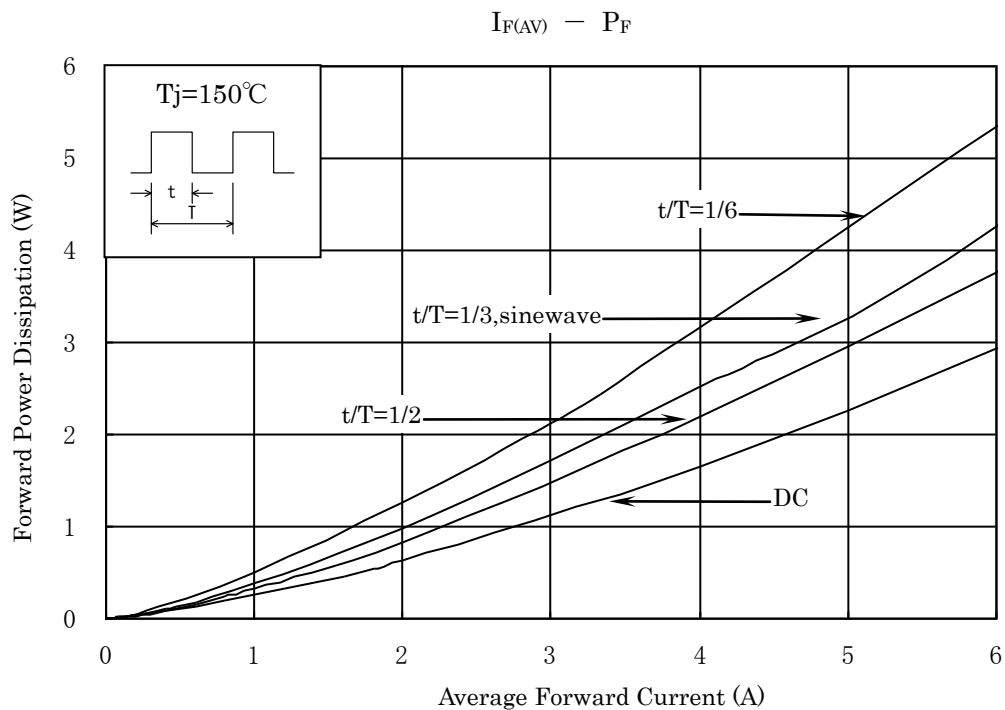
9.3 Inner Structure and Material List

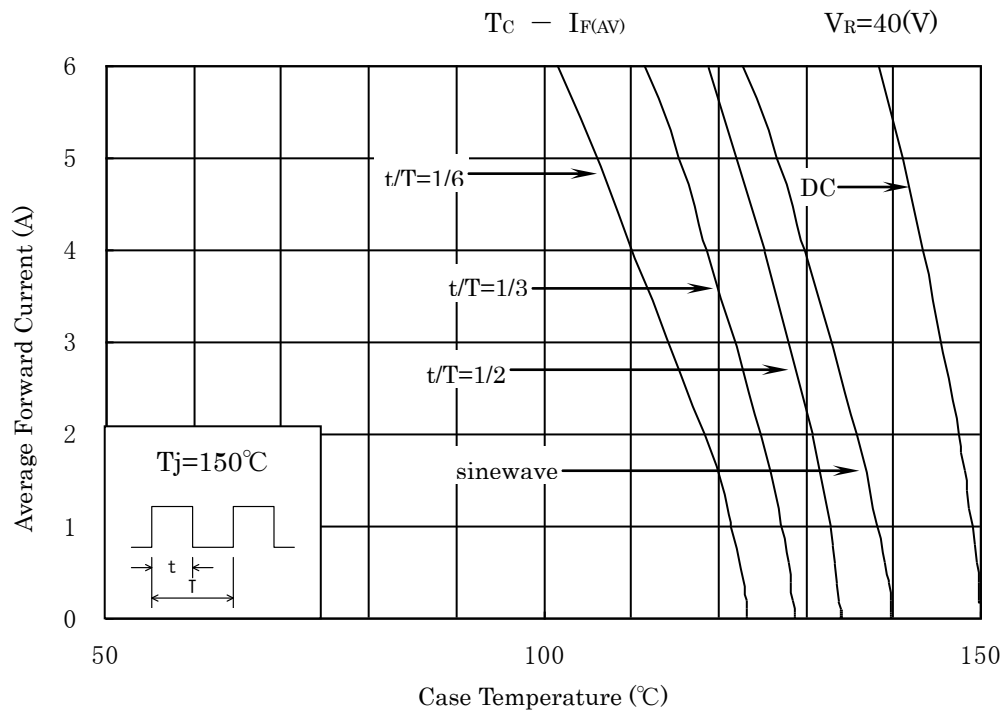


No.	Name of part	Materials
①	Frame: Heat Sink	Nickel Plated Copper
②	Chip	Silicon
③	Inner Leads	Aluminum Wire
④	Resin body	Epoxy Resin
⑤	Frame: Pin	Nickel Plated Copper + Solder Dipped

Weight of products: Approx. 2.1g

10. Characteristics





† CAUTION/ WARNING

Remarks in using silicone grease for a heat-sink

When silicone grease is used in mounting this product on a heat-sink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce forced stress.

Volatile type silicone grease may produce cracks after elapse of long term, resulting in reducing heat radiation effect. Silicone grease with low consistency (hard grease) may cause cracks in the mold resin when screwing the product to a heat-sink.

Depending on silicone grease to be used base oil separated from the silicone grease may penetrate into the product through possible thinner gaps between the mold resin and the lead-frame to cause wire breakage or cracks in the mold resin by swelling the coating material inside the product, resulting in the shorter product life. Therefore, silicone grease which contains base oil not causing swelling of coating materials must be selected.

Our recommended silicone grease for heat radiation purpose which will not cause any adverse effect on the product life is indicated below:

Type	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Toshiba Silicone Co., Ltd.
SC102	Dow Corning Toray Silicone Co., Ltd.

(2) Mounting Method of Heatsink

● Torque when Tightening Screws Mounting

Thermal resistance increases when tightening torque is small, and radiation effects are decreased. When the torque is too high, the screw can cut, the heatsink can be deformed, and/or distortion can be arise in the product's frame. To avoid these problems, Table1. show the recommended tightening torque for each product type.

Table1. Screw Tightening Torque

Package			Screw Tightening Torque
MT25	FM20	(TO-220 & Full Mold)	0.490 to 0.686 N · m (5 to 7 kgf · cm)
MT100	FM100	(TO-3P & Full Mold)	0.686 to 0.882 N · m (7 to 9 kgf · cm)

● Diameter of hole of heatsink: Less than 4mm φ

As the slack of press mold for making the hole will be the cause of resin crack at the mounting, please pay special attention for that.

(3) Others

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